

# Circuit Board Mounted Flux Gate Current Sensor DXE60-B2/55

 $I_{PN} = 60 A$ 

The DXE60-B2/55 is a advanced Circuit Board Mounted flux gate current sensor that use high technology to bring the best combination of performance and reliability, It is rated for a primary current measurement range of  $\pm$ 60A dc with the accuracy  $\pm$ 0.05%. It is calibrated and temperature compensated for improved accuracy using multi-point temperature characterization.



#### DIFFERENTIATION

- Convenience: Can be directly installed on the PCB board, ensuring accuracy while saving installation space
- high-voltage isolation: Ensure the safety and reliability of electrical equipment, and avoid mutual interference of currents between electrical equipment
- Accuracy: Multi-point temperature characterization and calibration for improved accuracy over temperature range.
- Magnetic immunity: Flux gate configuration and optimized magnetic circuit allow for excellent performance in diverse magnetic environments.
- Flexible: Customizable on-board firmware to meet specific application requirements.

#### **Features**

- Easy installation
- Excellent accuracy
- Very good linearity
- Low temperature drift
- Wide frequency bandwidth
- Optimized response time

# **Application Domain**

- Battery testing equipment
- Battery production equipment
- DC power supply equipment
- Electronic load equipment
- Power control



# **Electrical data**

Parameter	Minimum value	Standard value	Maximum value	Condition
Rated input current IPN=		±60 Adc		/
Measure range IPM=			±72 Adc	1Min/Hour
Power supply voltage Vc	±11Vdc		±16Vdc	Full range
Current consumption Ic	±20 mA	±80 mA	±92 mA	I <sub>PM</sub> range
Current change K <sub>N</sub>		1000:1		Input : Output
Rated output current IsN		60 mA		Rated input current
Measuring resistance RM		<b>30</b> Ω	<b>50</b> Ω	

# Accuracy- Dynamic Parameter

Project	Symbol	Test conditions	N	Unit		
Projeci	Symbol		minimum	standard	maximum	Unit
Acouroov	Xe	@0%~40%Ipn			0.012	А
Accuracy		@40%Ірм~Ірм			0.05	%RD
Ratio error	X	@0%~40%Ipn			0.012	А
	XGe	@40%Ірм~Ірм			0.02	%RD
Angle error	XPe				0.02	crad
Linearity	٤L				100	ppm
Temperature drift coefficient	тсі				10	ppm/K
Time drift coefficient	тт				10	ppm/month
Power supply anti-interference	TV				10	ppm/V
Zero offset current	lo	25±10℃			0.012	mA
Zero offset current	Іот	Within the full operating temperature range			±0.02	mA
Ripple current	In	DC-10Hz			20	ppm
Dynamic response time	Tr	di/dt=100A/us			1	us
		rise to 90% IPN				
Current following speed	di/dt		100			A/us
Bandwidth(- 3 dB)	F		0		100	kHz



#### **General characteristics**

Project	Symbol	Test conditions	Nu	Linit		
			minimum	standard	maximum	Unit
Operating temperature range	TA		-40		85	°C
Storage Temperature Range	Ts		-45		85	°C
Weight	m			20g±5g		g

# **Safety characteristics**

Project		Symbol	Test conditions	Numerical value			Unit
				minimum	standard	maximum	
Withstand voltage	Between primary and secondary edges	Vd	50Hz,1min		2.5		KV
Transient isolation withstand voltage	Between primary and secondary edges	Vw	50us		5		ΚV

2.32

28.00

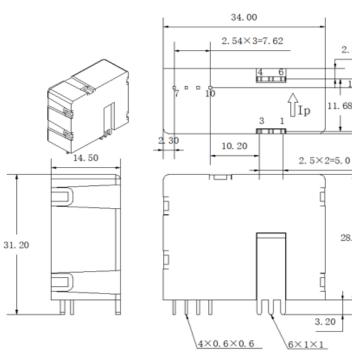
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3.20

0.50

11.68

# Mechanical dimension (mm)



接线定义						
1 3	Ip+	7	OUT	8	+15V	
4 6	Ip-	9	-15V	10	GND	



#### **Mechanical characteristics**

- General tolerance: ± 0.5 mm
- Connector: 2510-4P (spacing 2. 54MM)

### NOTE

• When the direction of the input current IP is consistent with the direction indicated by the arrow in the outline drawing, the output current IS is in the forward direction.

• Please try to locate the primary conductor at the center of the probe aperture as much as possible.

• The through-hole is made of metal material, so the through-hole wire cannot be an exposed cable. The through-hole wire must be insulated.

- This module is a standard sensor, please contact us for special applications.
- We reserve the right to modify this sensor manual without prior notice.